TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

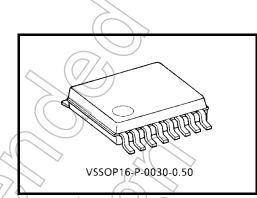
TC7MP01FK

Low-Voltage Triple Gate(6-input AND + 4-input OR + inverter)

The TC7MP01FK is a high-performance CMOS triple gate (6-input AND + 4-input OR + inverter). Desinged for use in 1.8 V, 2.5 V, or 3.3 V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is also designed with overvoltage tolerant inputs and outputs up to $3.6 \ensuremath{\mathrm{V}}.$

All inputs are equipped with protection circuits against static discharge.



Weight: 0.03 g (typ.)

Features

• Low-voltage operation : Vcc = 1.65 to 3.6V

Quiescent supply current : I_{CC} = 2μA (max) (V_{CC}=3.6V)

• High-speed operation : 6 input AND

tpd=3.7ns (max) (Vcc= $3.3\pm0.3V$) tpd=5.5ns (max) (Vcc= $2.5\pm0.2V$) tpd=11.0ns (max) (Vcc= $1.8\pm0.15V$)

TP -----

4 input OR

tpd=3.5ns (max) (Vcc=3.3 \pm 0.3V) tpd=5.0ns (max) (Vcc=2.5 \pm 0.2V) tpd=10.0ns (max) (Vcc=7.8 \pm 0.15V)

INV.

 $\begin{array}{l} \rm tpd=3.8ns~(max)~(Vcc=3.3\pm0.3V)\\ \rm tpd=5.2ns~(max)~(Vcc=2.5\pm0.2V)\\ \rm tpd=9.5ns~(max)~(Vcc=1.8\pm0.15V) \end{array}$

• Output current

: I_{OH}/I_{OL}=±12mA (min) (V_{CC}=3.0V) : I_{OH}/I_{OL}=±9mA (min) (V_{CC}=2.3V) : I_{OH}/I_{OL}=±2mA (min) (V_{CC}=1.65V)

• Latch-up performance

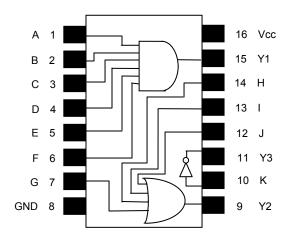
• ESD performance : Machine model $\geq \pm 200 \text{ V}$ Human body model $\geq \pm 2000 \text{ V}$

: ±300mA

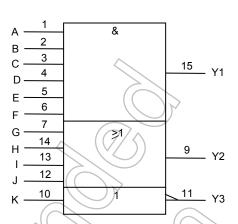
Ultra-small package : VSSOP(US16)

Power-down protection provided on all inputs and outputs.

Pin Assighment (top view)



IEC Logic Symbol



Truth Table (AND Logic)

А	В	С	D	_ \E	F	Y1//
	_		_		4	
L	Х	Х	Х	1 (x)	X C	F
х	L	х	x 4(×	x C	
х	×	L	×	x	(X)) L
х	×	×		> x	(x))	L
х	×	×	(x))	x	L
х	x	x	x	x) -	L
Н	Н	H () H	Н	// Н	Н

Truth Table (OR Logic)

G	/A)	J	Y2
Н	x /	x	X)) н
Х	H	x C	x	Н
x	x	Н	X	Н
x	× ,	x	H	Н
L	7	1	L	L

Truth Table (INV. Logic)

	/ _
K	Y3
Ĺ	Н
Н	L

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	-0.5 to 4.6	V	
DC input voltage	V _{IN}	-0.5 to 4.6	V	
DC output voltage	\/	-0.5 to 4.6 (Note 2)	V	
DC output voltage	V _{OUT}	-0.5 to V _{CC} +0.5(Note 3)		
Input diode current	I _{IK}	-50	mA	
Output diode current	lok	±50 (Note 4)	_ mA	
DC output current	lout	±50	// mA	
DC Vcc/ground current	I _{CC} /I _{GND}	±100	mA	
Power dissipation	PD	180	mW	
Storage temperature	T _{stg}	-65 to 150	°C	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: V_{CC}=0V

Note 3: High or low state.

Note 4: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	Vcc (1.65 to 3.6	V	
		1.2 to 3.6 (Note 2)		
DC input voltage	VIN	-0.3 to 3.6	V	
DC/output voltage	Volum	0 to 3.6 (Note 3)	V	
BC dutput voltage	VOUT	0 to V _{CC} (Note 4)	V	
		±12 (Note 5)		
Output current	I _{OH} /I _{OL}	±9 (Note 6)	mA	
	\vee	±2 (Note 7)		
Operating Temperature	Topr	-40 to 85	°C	
Input rise and fall time	dt / dv	0 to 10 (Note 8)	ns/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

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Note 2: Data retention only

Note 3: V_{CC}=0V

Note 4: High or low state

Note 5: V_{CC}=3.0 to 3.6V

Note 6: V_{CC}=2.3 to 2.7V

Note 7: V_{CC}=1.65 to 1.95V

Note 8: V_{IN}=0.8 to 2.0V, V_{CC}=3.0V

Electrical Characteristics

DC Characteristics (Ta=-40 to 85°C, 2.7V<V_{CC} ≤ 3.6V)

Characteris	stics	Symbol	Test	Test condition		Min	Max	Unit
Input Voltage	H-level	V _{IH}	-		2.7 to 3.6	2.0	-	V
iliput voltage	L-level	V _{IL}		-	2.7 to 3.6	<u></u>	0.8	V
				I _{OH} = -100μA	2.7 to 3.6	V _{CC} - 0.2	-	
	H-level	V _{OH}	V _{IN} =	I _{OH} = -6mA	2.7	2.2	-	
	H-level	V0H	V _{IH} orV _{IL}	I _{OH} = -9mA	3.0	7/\2.4	-	_ v
Output valtage				I _{OH} = -12mA	3.0	2.2	-	
Output voltage	Linual		V _{IN} =	I _{OL} = 100μA	2.7 to 3.6	-	0.2	
		Mari		I _{OL} = 6mA	2.7	_	0.4	
	L-level	V _{0L}		I _{OL} = 9mA	3.0	- ((0.4	
				I _{OL} = 12mA	3.0	- 0	0.55	
Input leakage	current	I _{IN}	V _{IN} =(to 3.6V	2.7 to 3.6	(-	±2.0	μA
Power-off leakag	ge current	l _{OFF}	V _{IN} , V _{OL}	V _{IN} , V _{OUT} =0 to 3.6V		7 ~ - ~ 7 /	2.0	μA
			V _{IN} =V _C	V _{IN} =V _{CC} or GND		3///	2.0	μA
Quiescent supply current		ΔI _{CC}		V _{IN} =V _{CC} - 0.6V (per input)		2)	750	μΑ

DC Characteristics (Ta=-40 to 85°C, 2.3V ≤ V_{CC} ≤ 2.7V)

Characteristics		Symbol	Test	condition	V _{CC} (V)	Min	Max	Unit
Input voltage	H-level))	-	2.3 to 2.7	1.6	-	V
iliput voltage	L-level	VJL		-	2.3 to 2.7	-	0.7	v
				l _{OH} =-100μA	2.3 to 2.7	V _{CC} - 0.2	-	
	H-level V _{OH}		VIN=	I _{OH} = -3mA	2.3	2.0	-	
		VOH	VIH or VIL	I _{OH} = -6mA	2.3	1.8	-	
Output voltage		\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \		OH= -9mA	2.3	1.7	-	V
	L-level V ₀		V _{IN} =	I _{OL} = 100μA	2.3 to 2.7	-	0.2	
>		V _{0L}		I _{OL} = 6mA	2.3	-	0.4	
		d	11110.11	I _{OL} = 9mA	2.3	-	0.6	
Input leakage	Input leakage current V _{IN} =0 to 3.6V		=0 to 3.6V	2.3 to 2.7	-	±2.0	μA	
Power-off leakage	ge current	loff.	V _{IN} ,V _{OUT} =0 to 3.6V		0	-	2.0	μΑ
Quiescent suppl	y current	Icc	V _{IN} =V	CC or GND	2.3 to 2.7	-	2.0	μΑ

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DC Characteristics (Ta=-40 to 85°C, 1.65V ≤ V_{CC}<2.3V)

Characteristics Symbol Test condit		condition	V _{CC} (V)	Min	Max	Unit		
Input voltage	H-Level	V_{IH}		-		1.65 to 2.3 0.7 × V _{CC}		V
input voitage	L-Level	V _{IL}	-		1.65 to 2.3	-	0.13 × V _{CC}	V
	H-Level	V _{0H}	V _{IN} =	I _{OH} =-100μA	1.65	V _{CC} -0.2	-	
Output voltage	i i-Levei	V0H	V _{IH} orV _{IL}	I _{OH} =-2mA	1.65	1.3	-	V
	L-Level	V _{0L}	V _{IN} = V _{IH} orV _{IL}	I _{OL} =2mA	1.65		0.2	-
Input leak	age current	I _{IN}	V _{IN} =0 to 3.6V		1.65	()) -	±2.0	μΑ
Power-off le	akage current	loff	V _{IN} , V _{OUT} =0 to 3.6V		0		2.0	μΑ
Quiescent s	supply current	Icc	V _{IN} =V ₀	CC or GND	1.65	-	2.0	μΑ

AC Characteristics (Ta=-40 to 85°C, Input: tr=tf=2.0ns, CL=30pF, RL=500Ω)

Characteristics	Symbol	Test co	ondition	V _{CC} (V)	Min	Max	Unit
		4(1.8±0.15	1.0	11.0	
		6 input AND		2.5±0.2	0.8	5.5	
		7(//	> _	3.3±0.3	0.6	3.7	
Propagation delay time		4()	Finda	1.8±0.15	1.0	10.0	ns
	t _{pLH} t _{pHL}	4 input OR	Figure 1, Figure 2	2.5±0.2	0.8	5.0	
			9	3,3±0.3	0.6	3.5	
				1.8±0.15	1.0	9.5	
) INV.		2.5±0.2	0.8	5.2	
				3.3±0.3	0.6	3.8	
	(\langle / \rangle)			1.8±0.15	-	0.5	
Output to output skew	tostH tosHL		(Note)	2.5±0.2	-	0.5	ns
	JUSTIL			3.3±0.3	-	0.5	

For C_L=50pF, add approximately 300ps to the AC maximum specification.

Note: Parameter guaranteed by design.

(tosLH=|tpLHm-tpLHn|, tosHL=|tpHLm-tpHLn|)

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Capacitive Characteristics (Ta=25°C)

Characteristics	Symbol	Test (Condition	V _{CC} (V)	Тур.	Unit
Input Capacitance	C _{IN}		-	1.8, 2.5, 3.3	6	pF
	C _{PD}	6 input AND	4	1.8, 2.5, 3.3	18	pF
Power dissipation capacitance		4 input OR	fin=10MHz Table1, (Note)	1.8, 2.5, 3.3	17	
		INV.	Tuble 1, (Note)	1.8, 2.5, 3.3	14	

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation.

I_{CC(opr)} =C_{PD}·V_{CC}·V_{IN}+I_{CC}/3 (per gate)

Table1 C_{PD} Test Condition

Function						Pin		179				
	1	2	3	4	5	6 7 8 9	10 (11	12	13	14	15	16
6 input AND	Р	Н	Н	Н	Н	H X G O	(X) (6)	X	Х	Х	С	٧
4 input OR	Х	Х	Х	Х	×	X P G C	X O	L	L	L	Ο	٧
INV.	Х	Х	Х	Х	X	X X G O	PC	X	Х	Х	Ο	٧

-Symbol explanation-

 $V=V_{CC}(+3.3V)$

X=Don't care(Fixed to V_{CC} or GND)

G=GND(0V)

O=Open

H=Logic1(V_{CC})

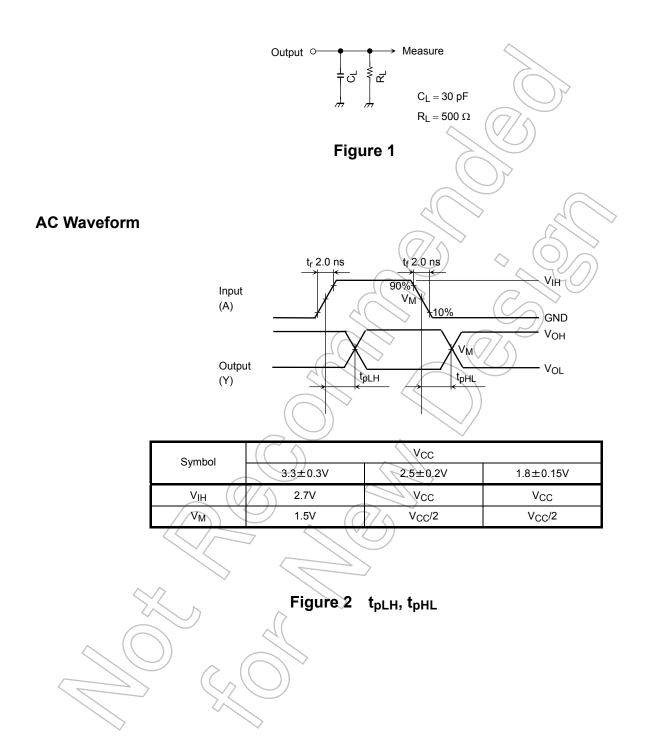
C=Connect a condenser(30pF) between output terminal and GND.

L=Logic0(GND)

P=Input pulse with 50% duty cycle.

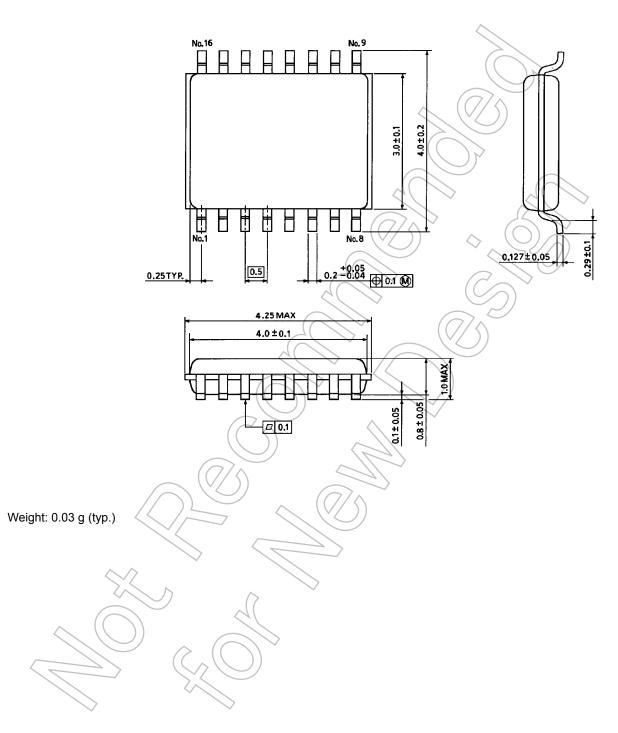


AC Test Circuit



Package Dimensions

VSSOP16-P-0030-0.50 Unit: mm



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